

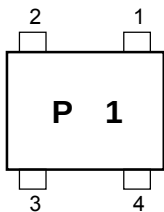
MT4S104T

UHF-SHF Low Noise Amplifier Application

FEATURES

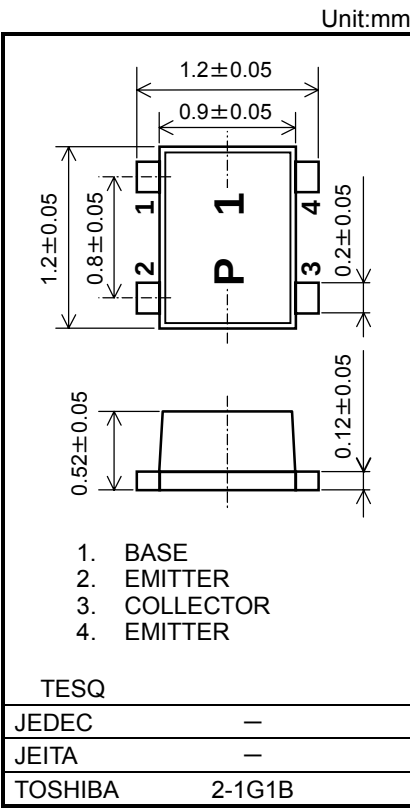
- Low Noise Figure :NF=1.25dB (@f=5.2GHz)
- High Gain:|S21e|<sup>2</sup>=10.5dB (@f=5.2GHz)

Marking



Maximum Ratings (Ta = 25°C)

| Characteristics             | Symbol           | Rating  | Unit |
|-----------------------------|------------------|---------|------|
| Collector-Base voltage      | V <sub>CBO</sub> | 6       | V    |
| Collector-Emitter voltage   | V <sub>CEO</sub> | 3       | V    |
| Emitter-Base voltage        | V <sub>EBO</sub> | 1.2     | V    |
| Collector-Current           | I <sub>C</sub>   | 10      | mA   |
| Base-Current                | I <sub>B</sub>   | 5       | mA   |
| Collector Power dissipation | P <sub>C</sub>   | 30      | mW   |
| Junction temperature        | T <sub>j</sub>   | 150     | °C   |
| Storage temperature Range   | T <sub>stg</sub> | -55~150 | °C   |



Weight: 0.0015 g

**Microwave Characteristics (Ta = 25°C)**

| Characteristics      | Symbol           | Test Condition                 | Min  | Typ. | Max  | Unit |
|----------------------|------------------|--------------------------------|------|------|------|------|
| Transition Frequency | $f_T$            | $V_{CE}=2V, I_C=7mA, f=2GHz$   | 21   | 25   | —    | GHz  |
| Insertion Gain       | $ S_{21e} ^2(1)$ | $V_{CE}=2V, I_C=7mA, f=2GHz$   | 15.5 | 18   | —    | dB   |
|                      | $ S_{21e} ^2(2)$ | $V_{CE}=2V, I_C=7mA, f=5.2GHz$ | —    | 10.5 | —    | dB   |
| Noise Figure         | NF(1)            | $V_{CE}=2V, I_C=5mA, f=2GHz$   | —    | 0.67 | 0.95 | dB   |
|                      | NF(2)            | $V_{CE}=2V, I_C=5mA, f=5.2GHz$ | —    | 1.25 | —    | dB   |

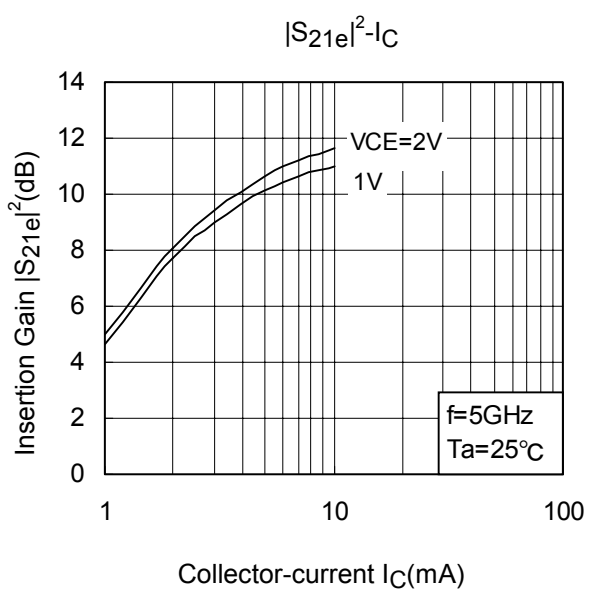
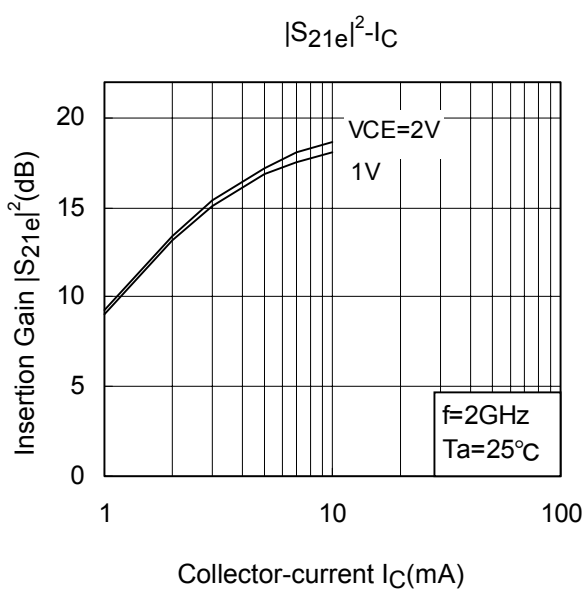
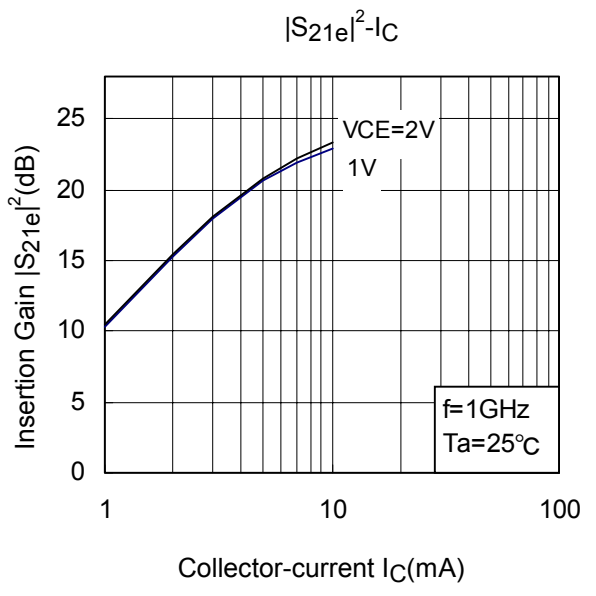
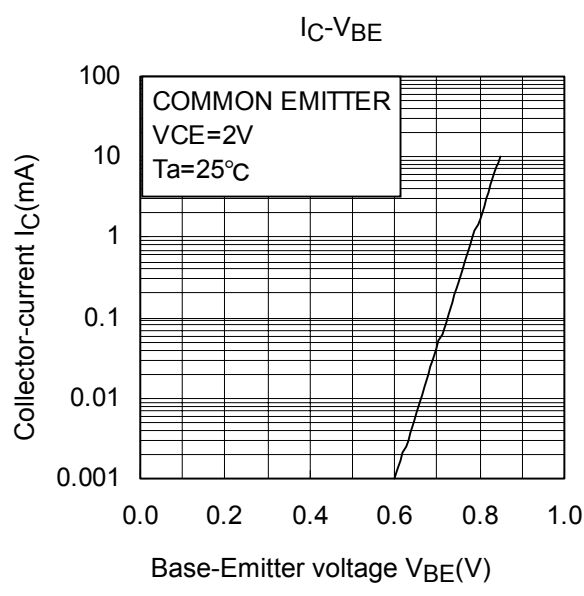
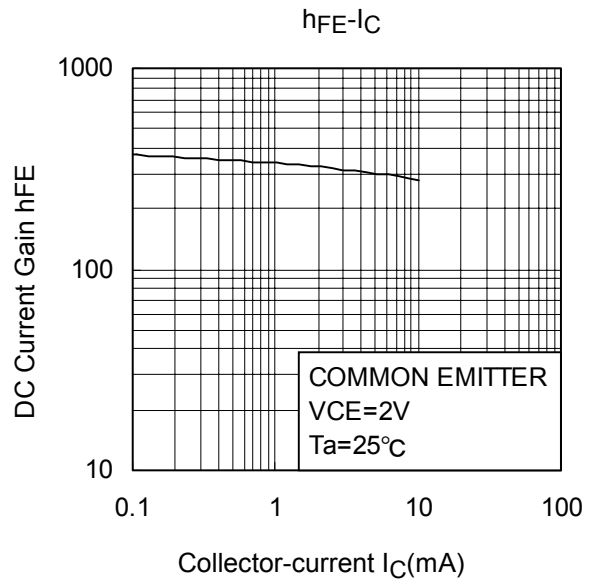
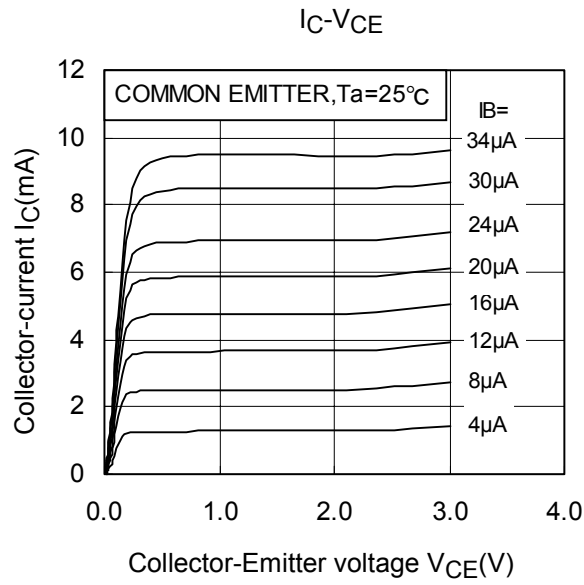
**Electrical Characteristics (Ta = 25°C)**

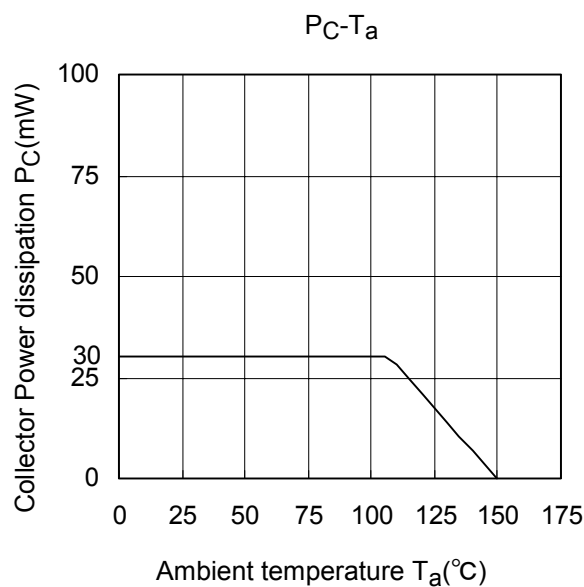
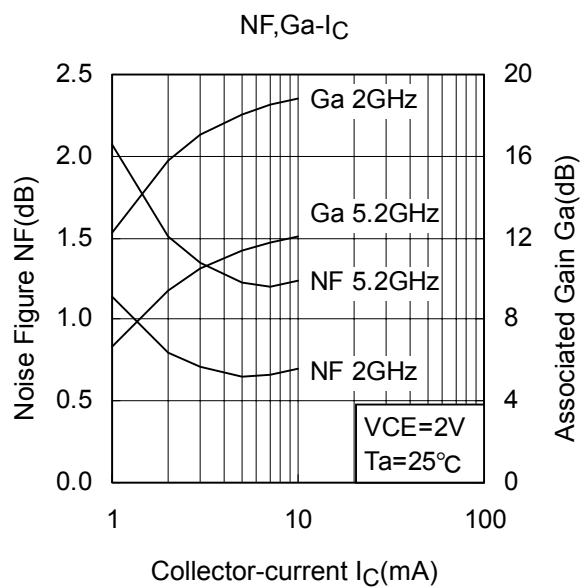
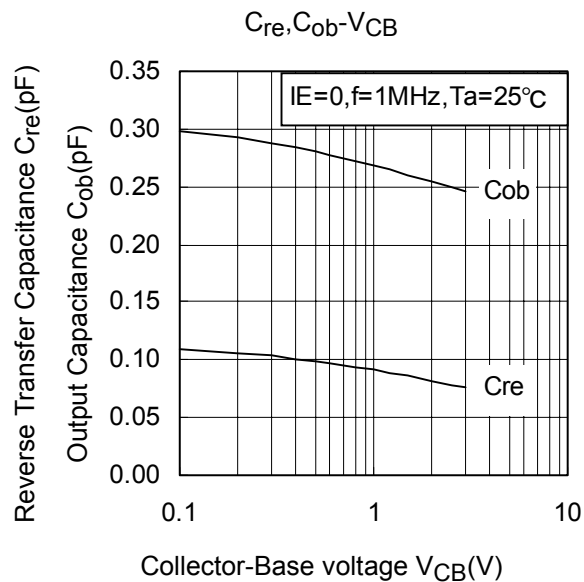
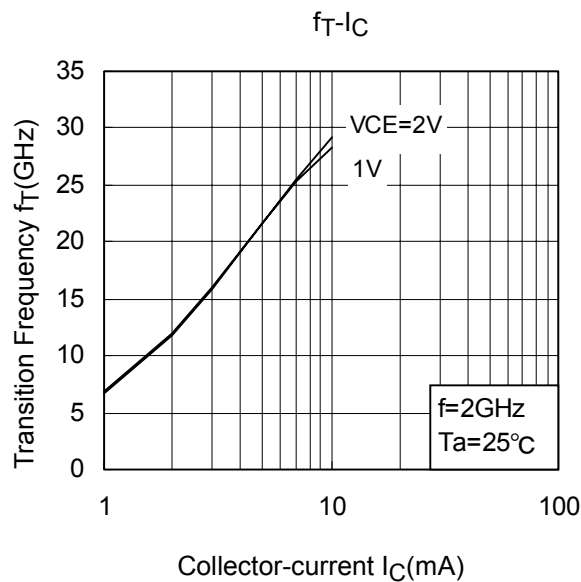
| Characteristics              | Symbol    | Test Condition                      | Min | Typ. | Max  | Unit    |
|------------------------------|-----------|-------------------------------------|-----|------|------|---------|
| Collector Cut-off Current    | $I_{CBO}$ | $V_{CB}=6V, I_E=0$                  | —   | —    | 1    | $\mu A$ |
| Emitter Cut-off Current      | $I_{EBO}$ | $V_{EB}=1V, I_C=0$                  | —   | —    | 1    | $\mu A$ |
| DC Current Gain              | $h_{FE}$  | $V_{CE}=2V, I_C=7mA$                | 200 | —    | 400  | -       |
| Output Capacitance           | $C_{ob}$  | $V_{CB}=2V, I_E=0, f=1MHz$          | —   | 0.26 | 0.5  | pF      |
| Reverse Transfer Capacitance | $C_{re}$  | $V_{CB}=2V, I_E=0, f=1MHz$ (Note 1) | —   | 0.09 | 0.18 | pF      |

**Note 1:**  $C_{re}$  is measured by 3 terminal method with capacitance bridge.

**Caution:** This device is sensitive to electrostatic discharge.

Please make enough tool and equipment earthed when you handle.





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